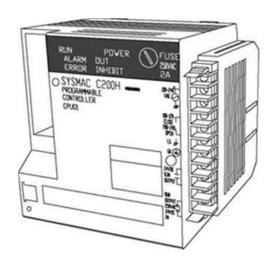
## **OMRON**

SYSMAC - System C200H CPUs

# C200H-CPU01-E C200H-CPU03-E



Presented by - MRO Electric and Supply Company, Inc.

For Product Needs:

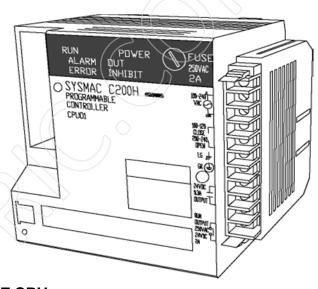
Email: <u>sales@MROELECTRIC.COM</u>

Call: **1-800-691-8511** Fax: **919-415-1614** 

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#### **General Information**

The CPUs provide a wide variety of features and capabilities for applications requiring simplified configuration and ease of use, maximum reliability and maintainability, and the ability to meet the need for future change and system expansion. A variety of CPUs are available with various memory and I/O configurations allowing selection based on application requirements.



#### C200H-CPU01-E/CPU03-E CPUs

#### High Spec, Small Rack Style, OEM Version

The C200H-CPU01-E and C200H-CPU03-E controllers offer big machine functions in a system designed ideally for basic OEM systems from 50 to 480 I/O. A wide variety of plug-in style I/O modules are available, including intelligent modules.

#### **Basic Configuration**

- Built-in 120 VAC (CPU01) or 24 VDC (CPU03) power supply
- Rack-style PLC with 3-, 5-, 8-, 10-slot racks
- Accepts two local expansion racks
- Accepts remote I/O racks

#### **CPU Features**

- 4K or 7K word program memory
- Expanded system memory (6,000 internal bits; 2,000 registers)
- 145 instructions
- Fast execution time (0.75-2.25 s per basic instruction)

#### **Special Features**

- Many intelligent I/O modules
- Versatile communications (Host Link, PLC-to-PLC, Remote I/O)
- ASCII/BASIC module for co-processing/communications

**C200H Comparison Table** 

ltem	C200H				
	CPU01-E	CPU03-E	CPU21-E	CPU23-E	CPU31-E
Group 2 High-density I/O Module compatibility C200H-ID216/ID217/OD218/OD219	No	No	Yes	Yes	Yes
Error history	No	No	Yes	Yes	Yes
Clock/calendar*	No	No	Yes	Yes	Yes
Forced Status Hold Bit (SR 25211)	No	No	Yes	Yes	Yes
TERMINAL mode for Programming Console	No	No	Yes	Yes	Yes
Optional instructions 1 (refer to Instruction Set Section):No REVERSIBLE WORD SHIFT - RWS(17) SCAN TIME - SCAN(18) MULTI-WORD COMPARE - MCMP(19) LONG MESSAGE - LMSG(47) TERMINAL MODE - TERM(48) SET SYSTEM - SET(49) DOUBLE COMPARE - CMPL(60) COLUMN-TO-WORD - CTW(63) WORD-TO-COLUMN - WTC(64) HOURS-TO-SECONDS - HTS(65) SECONDS-TO-HOURS - STH(66) VALUE CALCULATE - VCAL(69) MULTIPOINT I/O REFRESH - MPRF(61)		No	Yes	Yes	Yes
Optional instructions 2 (refer to Instruction Set Section):No PID CONTROL - PID(*) SCALING - SCL(*) TOTALIZING TIMER - TTIM(87) 2's COMPLEMENT - NEG(*) DOUBLE 2's COMPLEMENT - NEGL(*) FIND MINIMUM - MIN(*) FIND MAXIMUM - MAX(*) TENKEY INPUT - TKY(*) MATRIX INPUT - MTR(*) ASCII-to-HEX - HEX(*) AVERAGE - AVG(*) SUM - SUM(*) FAILURE POINT DETECT - FPD(*) Note For complete list refer to instruction set section.		No	No	No	No
SYSMAC NET, SYSMAC LINK network compatibility and instructions:  NETWORK SEND - SEND(90)  NETWORK RECEIVE - RECV(98)	No	No	No	No	Yes
Power supply	AC	DC	AC	DC	AC
nternal logic current capacity (for I/O modules)	1.6 A	1.6 A	3.2 A	1.6 A	3.0 A

 $<sup>^*</sup>$ A clock is built into the C200H-CPU31-E; the C200H-CPU21-E and C200H-CPU23-E can use the clock built into some of the Memory Packs. (Refer to Standard Parts.)



#### **C200HS Comparison Table**

ltem	C200HS					
	CPU01-E	CPU03-E	CPU21-E	CPU23-E	CPU31-E	CPU33-E
Group 2 High-density I/O Module compatibility C200H-ID216/ID217/OD218/OD219	Yes	Yes	Yes	Yes	Yes	Yes
Error history	Yes	Yes	Yes	Yes	Yes	Yes
Clock/calendar*	Yes	Yes	Yes	Yes	Yes	Yes
Forced Status Hold Bit (SR 25211)	Yes	Yes	Yes	Yes	Yes	Yes
TERMINAL mode for Programming Console	Yes	Yes	Yes	Yes	Yes	Yes
Optional instructions 1 (refer to Instruction Set Section):  REVERSIBLE WORD SHIFT - RWS(17) SCAN TIME - SCAN(18) MULTI-WORD COMPARE - MCMP(19) LONG MESSAGE - LMSG(47) TERMINAL MODE - TERM(48) SET SYSTEM - SET(49) DOUBLE COMPARE - CMPL(60) COLUMN-TO-WORD - CTW(63) WORD-TO-COLUMN - WTC(64) HOURS-TO-SECONDS - HTS(65) SECONDS-TO-HOURS - STH(66) VALUE CALCULATE - VCAL(69) MULTIPOINT I/O REFRESH - MPRF(61)	Yes	Yes	Yes	Yes	Yes	Yes
Optional instructions 2 (refer to Instruction Set Section):  PID CONTROL - PID(*)  SCALING - SCL(*)  TOTALIZING TIMER - TTIM(87)  2's COMPLEMENT - NEG(*)  DOUBLE 2's COMPLEMENT -  NEGL(*)  FIND MINIMUM - MIN(*)  FIND MAXIMUM - MAX(*)  TENKEY INPUT - TKY(*)  MATRIX INPUT - MTR(*)  ASCII-to-HEX - HEX(*)  AVERAGE - AVG(*)  SUM - SUM(*)  FAILURE POINT DETECT - FPD(*)  Note For complete list refer to instruction set section.	Yes	Yes	Yes	Yes	Yes	Yes
SYSMAC NET, SYSMAC LINK network compatibility and instructions: NETWORK SEND - SEND(90) NETWORK RECEIVE - RECV(98)	No	No	No	No	Yes	Yes
Power supply	AC	DC	AC	DC	AC	DC
Internal logic current capacity (for I/O modules)	3.9 A	2.3 A	3.9 A	2.3 A	3.9 A	2.3 A
Built-In RS232C PORT	No	No	Yes	Yes	Yes	Yes

 $<sup>^{*}</sup>$  A clock is built into the C200H-CPU31-E; the C200H-CPU21-E and C200H-CPU23-E can use the clock built into some of the Memory Packs. (Refer to Standard Parts.)



**C200H Specifications** 

Part number	C200H-CPU01-E/CPU03-E	C200H-CPU21-E/CPU23-E	C200H-CPU31-E
Main Control Element	MPU, CMOS, LS-TTL		<u>.                                      </u>
Programming languages	Ladder diagram		
Instruction set	145 (12 basic instructions + 133 special instructions)	168 (12 basic instructions + 156 special instructions)	172 (12 basic instructions + 160 special instructions)
Instruction length	1 to 4 words/instruction, 1 address/ins	truction	
Execution time	0.75 to 2.25 as (basic instructions) 34 to 724 as (function no. instructions	)	
I/O control method	Cyclic, programmed, scheduled, and	zero-cross refreshing	
Control input signal	START INPUT (in RUN mode, PLC op opened; 24 VDC, 10 mA)	erates when contacts are closed and s	tops when contacts are
Control output signal	RUN OUTPUT; dry contact (contacts a 2 A, 250 VAC (resistive load, p.f. = 1)		
Memory protection	Status of HR bits, AR bits, preset value during power failure. RAM Pack, batte protected. RAM Pack, capacitor back-clockfunction): Data areas protected. Eprotected. C200H-CPU31-E: Program	ry back-up: Program (including clock up: Program and data areas protecte EPROM Pack (with clockfunction): Clo	function) and data areas d. EEPROM Pack (without ockfunction and data area
Battery life	4 years at 25°C (77°F); shortened at t withi 1 week when ALARM indicator b	emperatures higher than 25C. Repla links.	ce battery with new one
Self-diagnostics	Errors for CPU failure, Battery, Scan fil Special I/O Modules, CPU Bus Module	me, Memory failure, I/O bus, I/O verify, es	Remote I/O, Link error,
Agency approvals	UL listed, file number: E95399 CSA certified, file number: LR51460		

#### **Memory**

Wichiol y				
Memory capacity	6,974 words (with 8K-word memory)	<u></u>		
Internal relay IR bits	Standard I/O Modules: 480 (00000 through 02915)			
()	I/O Modules mounted to Remote Expansion Racks and Special I/O Modules 3,296 (03000 through 23515)	I/O Modules mounted to Remote Expansion Racks and Special I/O Modules 3,296 (03000 through 23515) Group 2 High-density I/O Modules 320 (03000 through 04915)		
Special Relay (SR) bits	312 (23600 through 25507)			
Temporary relay (TR) bits	8 (TR 0 through 7)			
Holding relay (HR) bits	1,600 (HR 0000 through 9915)			
Auxiliary relay (AR) bits	448 (AR 0000 through 2715)			
Latching relay (LR) bits	1,024 (LR 0000 through 6315)			
Timers/Counters	512 (TIM/CNT 000 through 511) TIMs: 0 through 999.9 s TIMHs: 0 through 99.99 s CNT: 0 through 9999 counts			

#### **C200HS Specifications**

Part number	C200HS-CPU01-E/CPU03-E	C200HS-CPU21-E/CPU23-E	C200HS-CPU31-E CPU33-E	
Main Control Element	MPU, CMOS, LS-TTL			
Programming languages	Ladder diagram			
Instruction set	239 (14 basic instructions + 225 special instructions)	239 (14 basic instructions + 225 special instructions)	243 (14 basic instructions + 299 special instructions)	
Instruction length	1 to 4 words/instruction, 1 address/instruction			
Execution time	0.375-1.313 s (basic instructions)	//		
I/O control method	Cyclic, programmed, scheduled, and zero-cross refreshing			
Control input signal	START INPUT (in RUN mode, PLC operates when contacts are closed and stops when contacts are opened; 24 VDC, 10 mA)			
Control output signal	RUN OUTPUT; dry contact (contacts are closed while PLC is in RUN mode; maximum switching capacity 2 A, 250 VAC (resistive load, p.f. = 1), 0.5 A, 250 VAC (inductive load, p.f. = 0.4), 2 A, 24 VDC)			
Memory protection	Status of HR bits, AR bits, preset value during power failure. RAM Pack, batter protected. RAM Pack, capacitor back-clock function): Data areas protected. E protected. C200H-CPU31-E: Program	of counters (CNT), and contents of d ry back-up: Program (including clock up: Program and data areas protecte EPROM Pack (with clock function): Cl	ata memory (DM) are retaine function) and data areas d. EEPROM Pack (without ock function and data area	
Battery life	4 years at 25C (77F); shortened at temperatures higher than 25C. Replace battery with new one within week when ALARM indicator blinks.			
Self-diagnostics	Errors for CPU failure, Battery, Scan time, Memory failure, I/O bus, I/O verify, Remote I/O, Link error, Special I/O Modules, CPU Bus Modules			
Agency approvals	UL listed, file number: E95399 CSA certified, file number: LR51460			

### Memory

Memory capacity	15.2k words (with 16k word memory)
Internal relay (IR) bits	Standard I/O Modules: 480 (00000 through 02915)
	I/O Modules mounted to Remote Expansion Racks and Special I/O Modules 6688 (03000 through 23515, 30000-51115) Group 2 High-density I/O Modules 320 (03000 through 04915)
Special Relay (SR) bits	1016 (23600 through 25507 and 25600 through 29915)
Temporary relay (TR) bits	8 (TR 0 through 7)
Holding relay (HR) bits	1,600 (HR 0000 through 9915)
Auxiliary relay (AR) bits	448 (AR 0000 through 2715)
Latching relay (LR) bits	1,024 (LR 0000 through 6315)
Timers/Counters	512 (TIM/CNT 000 through 511) TIMs: 0 through 999.9 s TIMHs: 0 through 99.99 s CNT: 0 through 9999 counts

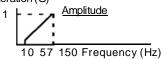
C200H/C200HS Specifications

Part number	C200H-CPU01-E/CPU03-E	C200H-CPU21-E/CPU23-E	C200H-CPU31-E	C200HS-CPU01-E/CPU03-E C200HS-CPU21-E/CPU23-E C200HS-CPU31-E/CPU33-E
Data memory	Read/write: 1,000 (DM 0000 t	hrough 0999)		Read/Write: 6144 (DM0000
(DM) words	Read only: 1,000 (DM 1000 th	rough 1999)		through 6143)
, ,	DM area as in Memory Park.			Read only: 512 (6144 through 6655) 3000 Word max. (DM7000 through 9999)
Program check	Program check (executed on s END missing, Instruction error (Program can be checked by	. ,	r LSS at three levels.	

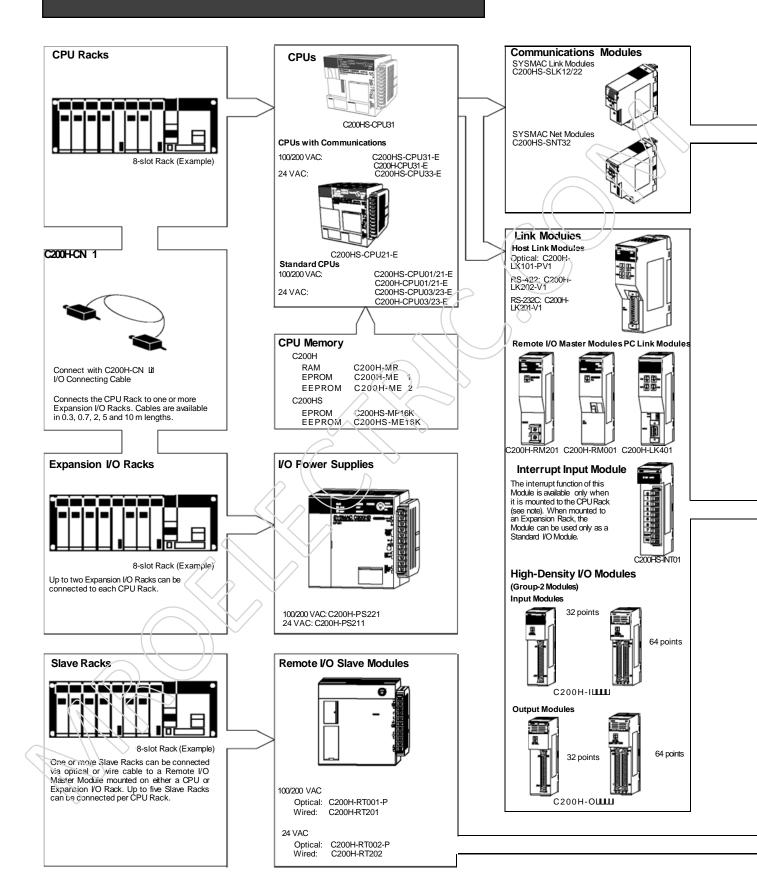
Part number	C200H-CPU01-E/CPU21-E/CPU31-E, C200HS-CPU01-E, C200HS-CPU21-E, C200HS-CPU31-E, C200H-PS221	C200H-CPU23-E, C200HS-CPU03-E, C200HS-CPU23-E, C200HS-CPU33-E, C200H-PS211	
Supply voltage	100 to 120/200 to 240 VAC selectable, 50/60 Hz	24 VDC	
Operating voltage range	85 to 132/170 to 264 VAC 20.4 to 26.4 VDC		
Power consumption	100 VA max.	50 W max.	
Surge current	30 A max.	30 A max.	
Output capacity	CPU01-E, 3 A, 5 VDC (1.6 A supplied to I/O Modules) CPU-21-E: 4.6 A, 5 VDC (3.2 A supplied to I/O Modules) CPU-31-E: 4.6 A, 5 VDC (3.0 A supplied to I/O Modules) HS-CPU01-E, HS-CPU21-E, HS-CPU31-E 4.6 A, 5 VDC (3.9 A supplied to I/O Modules) Expansion I/O Rack: 3 A, 5 VDC (2.7 A supplied to I/O Modules)	CPU03-E: 3 A, 5 VDC (1.6 A supplied to I/O Modules) CPU-23-E: 3 A, 5 VDC (1.6 A supplied to I/O Modules) HS-CPU03-E, HS-CPU23-E, HS-CPU33-E: 3 A, 5 VDC (2.3 A supplied to I/O Modules) Expansion I/O Rack: 3 A, 5 VDC (2.7 A supplied to I/O Modules)	
Fuse	2 A, 250 V, 5.2 dia. x 20 (MF51NR)	2 A, 125 V, 5.2 dia. x 20 (MF51NR)	
Input power supply	0.3 A, 24 VDC +10%/-20%		
Insulation resistance*	20 M between AC terminals and the GR terminal at 500 VDC		
Dielectric strength*	2,000 VAC, 50/60 Hz for 1 minute between AC terminals and hou 500 VAC, 50/60 Hz for 1 minute between DC terminals and hou Leakage current: 10 mA max.		
Noise immunity	1,500 Vp-p, pulse width: 100 ns to 1 nis, rise time: 1 ns (by noise	simulator)	
Vibration**	Mechanical durability: 10 to 35 Hz, 1 mm double amplitude (2.5 (When mounted on DIN track, 16.7 Hz, 1 mm double amplitude (0. Malfunction durability: 2 to 55 Hz, 2 G, in X, Y, and Z directions, tra 2 to 55 Hz, 0.3 G, in X, Y, and Z directions, for 20 minutes ea	5 G) in X, Y, and Z directions, for 1 hour each for 20 minutes each (When mounted on DIN	
Shock	10 G in X, Y, and Z directions, 3 times each		
Ambient temperature	Operating: 0 to 55C (0 to 45C for Programming Console) Storage: -20 to 65 C		
Humidity	35% to 85% (without condensation)		
Atmosphere	Must be free of the following: Corrosive gases; Abrupt temperature filings; Water, oil, or chemicals	e changes; Direct sunlight; Dust, salt, or meta	
Grounding	Less than 100 a		
Enclosure rating	IEC IP30 (mounted in a panel)		

Note \*Disconnect the LG terminal of the Power Supply Module from the GR terminal when performing insulation and dielectric strength tests. If the tests are performed with the LG and GR terminals short-circuited, the internal components will be damaged. Do not conduct a dielectric strength test on the C200H-CPU03-E, C200H-CPU23-E, C200H-PS211, C200H-RT002-P, or C200H-RT202 modules. The power supply input line and internal circuit of the 24 VDC power supply are not isolated from each other. If a dielectric strength test is conducted, the power supply will be damaged.

\*\*Acceleration (G)



## System Configuration



Note: Only one Interrupt Input Module can be used with a CPU.

## System Configuration

